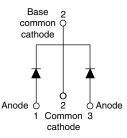


Vishay Semiconductors



Schottky Rectifier, 2 x 7.5 A





PRODUCT SUMMARY					
Package	TO-220AB				
I _{F(AV)}	2 x 7.5 A				
V _R	35 V, 45 V				
V _F at I _F	0.57 V				
I _{RM} max.	15 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Common cathode				
E _{AS}	7 mJ				

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The VS-MBR15...CT... center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	15	A			
V _{RRM}		35/45	V			
I _{FSM}	t _p = 5 μs sine	690	A			
V _F	7.5 A _{pk} , T _J = 125 °C	0.57	V			
TJ	Range	- 65 to 150	°C			

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-MBR1535CTPbF	VS-MBR1535CT-N3	VS-MBR1545CTPbF	VS-MBR1545CT-N3	UNITS		
Maximum DC reverse voltage	V _R	35	35	45	45	V		
Maximum working peak reverse voltage	V _{RWM}		55	40	44	v		

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	PARAMETER		TEST CONDITIONS		VALUES	UNITS		
Maximum average	per leg	I	$I_{F(AV)}$ T _C = 131 °C, rated V _R				7.5	
forward current	per device	IF(AV)			15			
Maximum peak one cycle non-repetitive surge		I _{ESM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V_{RRM} applied	690	A		
		1 OM	Surge applied at rated load condition half wave single phase 60 Hz		150			
Non-repetitive avalanche energ	Ivalanche energy per leg E_{AS} $T_J = 25 \text{ °C}, I_{AS} = 2 \text{ A}, L = 3.5 \text{ mH}$		7	mJ				
Repetitive avalanche current pe	er leg	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		2	А		

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RoHS

COMPLIANT

HALOGEN

FREE



VS-MBR15...CTPbF Series, VS-MBR15...CT-N3 Series

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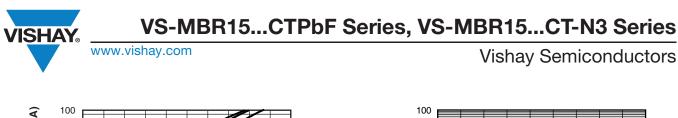
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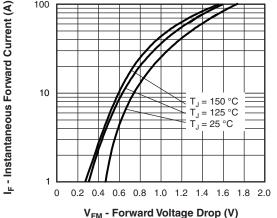
ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		15 A	T _J = 25 °C	0.84		
Maximum forward voltage drop	V _{FM} ⁽¹⁾	7.5 A	T 405 00	0.57	V	
		15 A	T _J = 125 °C	0.72		
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	$T_J = 25 \ ^\circ C$	Data d DO contra co	0.1	mA	
Maximum instantaneous reverse current		T _J = 125 °C	Rated DC voltage	15		
Maximum junction capacitance	CT	V_{R} = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 $^{\circ}\text{C}$		400	pF	
Typical series inductance	L _S	Measured from top of terminal to mounting plane		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs		

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHA	THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperatu	re range	TJ		- 65 to 150	°C		
Maximum storage temperatu	re range	T _{Stg}		- 65 to 175	U		
Maximum thermal resistance junction to case per leg	3	R _{thJC}	DC operation	3.0			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	°C/W		
Maximum thermal resistance, junction to ambient		R _{thJA}	DC operation	60			
Approvimeto weight				2	g		
Approximate weight				0.07	OZ.		
Mounting torque minimum maximum				6 (5)	kgf ⋅ cm		
				12 (10)	(lbf · in)		
Marking davias				MBR1	535CT		
Marking device			Case style TO-220AB		545CT		







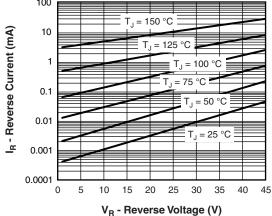


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

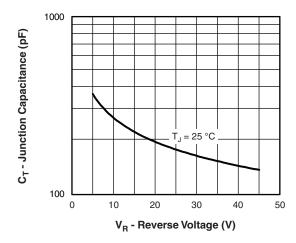
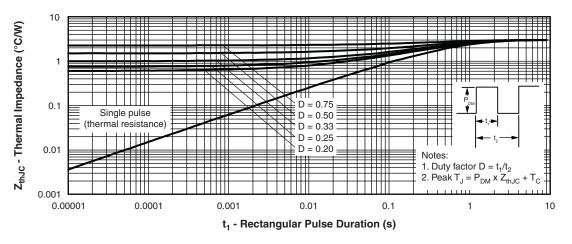
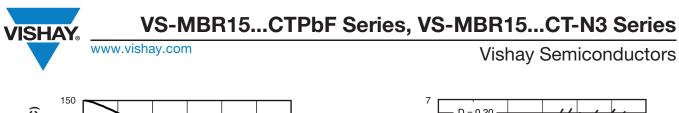


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)





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Average Power Loss (W)

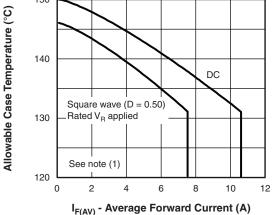
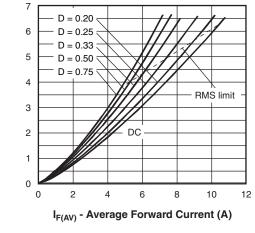
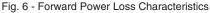


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current





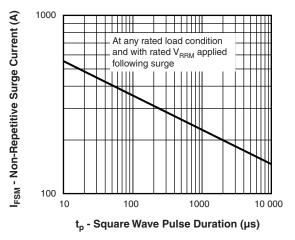


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \, x \, \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \, x \, \mathsf{I}_{\mathsf{R}} \ (1 - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{Rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

VS-MBR15...CTPbF Series, VS-MBR15...CT-N3 Series



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ORDERING INFORMATION TABLE

Device code	VS-	MBR	15	45	СТ	PbF	
		2	3	4	5	6	
	 Vishay Semiconductors product Schottky MBR series 						
	3 · 4 ·	- Current rating (15 = 15 A) 35 = 35 V - Voltage ratings 45 = 45 V					
	5 · 6 ·	- Env	ironmer	ntial part ntal digit		r d RoHS	

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-MBR1535CTPbF	50	1000	Antistatic plastic tube			
VS-MBR1535CT-N3	50	1000	Antistatic plastic tube			
VS-MBR1545CTPbF	50	1000	Antistatic plastic tube			
VS-MBR1545CT-N3	50	1000	Antistatic plastic tube			

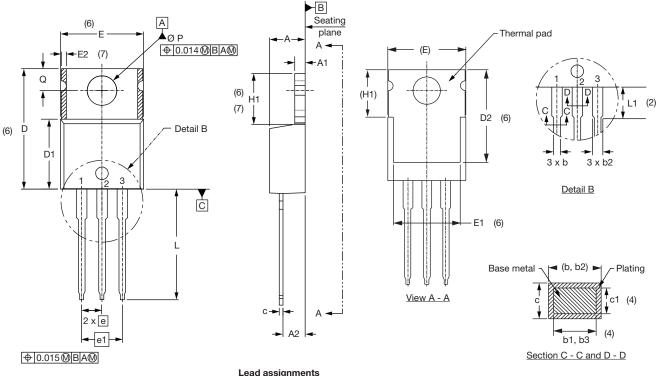
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95222					
Part marking information	TO-220AB PbF	www.vishay.com/doc?95225			
	TO-220AB -N3	www.vishay.com/doc?95028			
SPICE model		www.vishay.com/doc?95294			

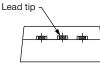


Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches





Leau	l as:	sign	me	пι
		-		

Diodes 1. - Anode/open

2. - Cathode 3. - Anode

	MILLIN	IETERS	INC		
SYMBOL			_	-	NOTES
	MIN.	MAX.	MIN.	MAX.	
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- ⁽³⁾ Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed $0.127 \text{ mm} (0.005^{\circ})$ per side. These dimensions are measured at the outermost extremes of the plastic body
- $^{\left(4\right) }$ Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1

SYMBOL	MILLIMETERS		INC	NOTES	
STWBUL	MIN.	MAX.	MIN.	MAX.	NUTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

Conforms to JEDEC outline TO-220AB

- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- Outline conforms to JEDEC TO-220, except A2 (maximum) and (8) D2 (minimum) where dimensions are derived from the actual package outline

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